# onsemi

### **PNP General-Purpose** Amplifier

## NSVT5401MR6

#### Features

- This Device Has Matched Dies
- AEC-Q101 Qualified and PPAP Capable
- These Devices are Pb–Free, Halogen Free/BFR Free and are RoHS Compliant

#### ABSOLUTE MAXIMUM RATINGS (Notes 1, 2)

 $(T_A = 25^{\circ}C, \text{ unless otherwise noted})$ 

Rating	Symbol	Value	Unit
Collector – Emitter Voltage	V <sub>CEO</sub>	-150	V
Collector – Base Voltage	V <sub>CBO</sub>	-160	V
Emitter-Base Voltage	$V_{\text{EBO}}$	-5.0	V
Collector Current – Continuous	۱ <sub>C</sub>	-600	mA
Operating and Storage Junction Temperature Range	T <sub>J</sub> , T <sub>STG</sub>	–55 to +150	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1. These ratings are based on a maximum junction temperature of 150°C.

 These are steady-state limits. onsemi should be consulted on applications involving pulsed or low-duty-cycle operations.

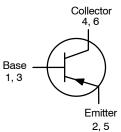
#### THERMAL CHARACTERISTICS (Note 3)

(T<sub>A</sub> =  $25^{\circ}$ C, unless otherwise noted)

Characteristic	Symbol	Max	Unit
Total Device Dissipation	PD	700	mW
Thermal Resistance, Junction-to-Ambient, Total	$R_{\thetaJA}$	180	°C/W

3. Device mounted on a 1 in 2 pad of 2 oz copper.

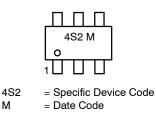
#### **ELECTRICAL CONNECTION**



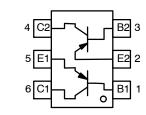


TSOT23 6-Lead CASE 419BL

#### MARKING DIAGRAM







#### **ORDERING INFORMATION**

Device	evice Package	
NSVT5401MR6T1G	TSOT23–6 (Pb–Free)	3000 / Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

#### NSVT5401MR6

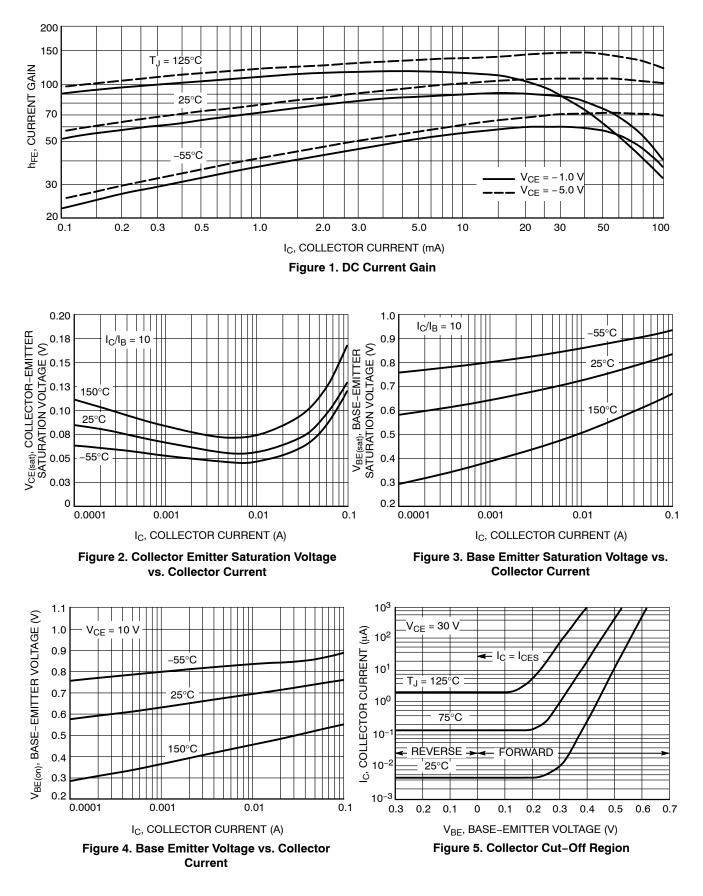
#### ELECTRICAL CHARACTERISTICS (T<sub>A</sub> = 25°C unless otherwise noted)

Parameter	Symbol	Test Condition	Min	Max	Unit
Collector-Emitter Breakdown Voltage (Note 4)	BV <sub>CEO</sub>	I <sub>C</sub> = -1.0 mA, I <sub>B</sub> = 0	-150	-	V
Collector-Base Breakdown Voltage	BV <sub>CBO</sub>	$I_{C} = -100 \ \mu A, \ I_{E} = 0$	-160	-	V
Emitter-Base Breakdown Voltage	BV <sub>EBO</sub>	I <sub>E</sub> = −10 μA, I <sub>C</sub> = 0	-5.0	-	V
Collector Cut-Off Current	I <sub>CBO</sub>	V <sub>CB</sub> = -120 V, I <sub>E</sub> = 0	-	-50	nA
		$V_{CB} = -120 \text{ V}, \text{ I}_{E} = 0, \text{ T}_{A} = 100^{\circ}\text{C}$	-	-50	μΑ
Emitter Cut-Off Current	I <sub>EBO</sub>	$V_{EB} = -3 V, I_{C} = 0$	-	-50	nA
DC Current Gain (Note 4)	h <sub>FE1</sub>	$V_{CE} = -5 \text{ V}, I_{C} = -1 \text{ mA}$	50	-	-
Variation Ratio of h <sub>FE1</sub> Between Die 1 and Die 2	DIVID1	h <sub>FE1</sub> (Die1) / h <sub>FE1</sub> (Die2)	0.9	1.1	-
DC Current Gain (Note 4)	h <sub>FE2</sub>	$V_{CE} = -5 \text{ V}, \text{ I}_{C} = -10 \text{ mA}$	60	240	-
Variation Ratio of h <sub>FE2</sub> Between Die 1 and Die 2	DIVID2	h <sub>FE2</sub> (Die1) / h <sub>FE2</sub> (Die2)	0.95	1.05	-
DC Current Gain (Note 4)	h <sub>FE3</sub>	$V_{CE} = -5 \text{ V}, \text{ I}_{C} = -50 \text{ mA}$	50	-	-
Variation Ratio of h <sub>FE3</sub> Between Die 1 and Die 2	DIVID3	h <sub>FE3</sub> (Die1) / h <sub>FE3</sub> (Die2)	0.9	1.1	-
Collector-Emitter Saturation Voltage (Note 4)	V <sub>CE</sub> (sat)	$I_{\rm C} = -10$ mA, $I_{\rm B} = -1$ mA	-	-0.2	V
		$I_{\rm C} = -50$ mA, $I_{\rm B} = -5$ mA	-	-0.5	
Base-Emitter Saturation Voltage	V <sub>BE</sub> (sat)	I <sub>C</sub> = -10 mA, I <sub>B</sub> = -1 mA	-	-1	V
(Note 4)		$I_{\rm C} = -50$ mA, $I_{\rm B} = -5$ mA	-	-1	
Base-Emitter On Voltage (Note 4)	V <sub>BE</sub> (on)	$V_{CE} = -5 \text{ V}, \text{ I}_{C} = -10 \text{ mA}$	-	-1	V
Difference of V <sub>BE</sub> (on) Between Die1 and Die 2	DEL	V <sub>BE</sub> (on)(Die) – V <sub>BE</sub> (on)(Die2)	-8	8	mV
Current Gain Bandwidth Product	f <sub>T</sub>	$V_{CE} = -10 \text{ V}, \text{ I}_{C} = -10 \text{ mA},$ f = 100 MHz	100	300	MHz
Output Capacitance	C <sub>ob</sub>	V <sub>CB</sub> = -10 V, I <sub>E</sub> = 0, f = 1 MHz	-	6.0	pF
Noise Figure	NF	$\begin{array}{l} V_{CE}=-5.0 \text{ V}, \text{ I}_{C}=-250 \ \mu\text{A}, \\ \text{R}_{S}=1.0 \ \text{k}\Omega \\ \text{f}=10 \ \text{Hz} \ \text{to} \ 15.7 \ \text{kHz} \end{array}$	-	8.0	dB

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions. 4. Pulse test: Pulse width  $\leq$  300 ms, duty cycle  $\leq$  2%

#### NSVT5401MR6

**TYPICAL PERFORMANCE CHARACTERISTICS** 



#### NSVT5401MR6

#### TYPICAL PERFORMANCE CHARACTERISTICS (continued)

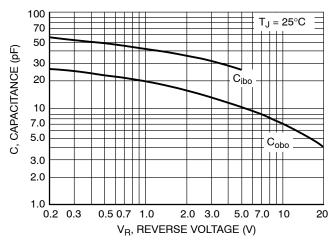
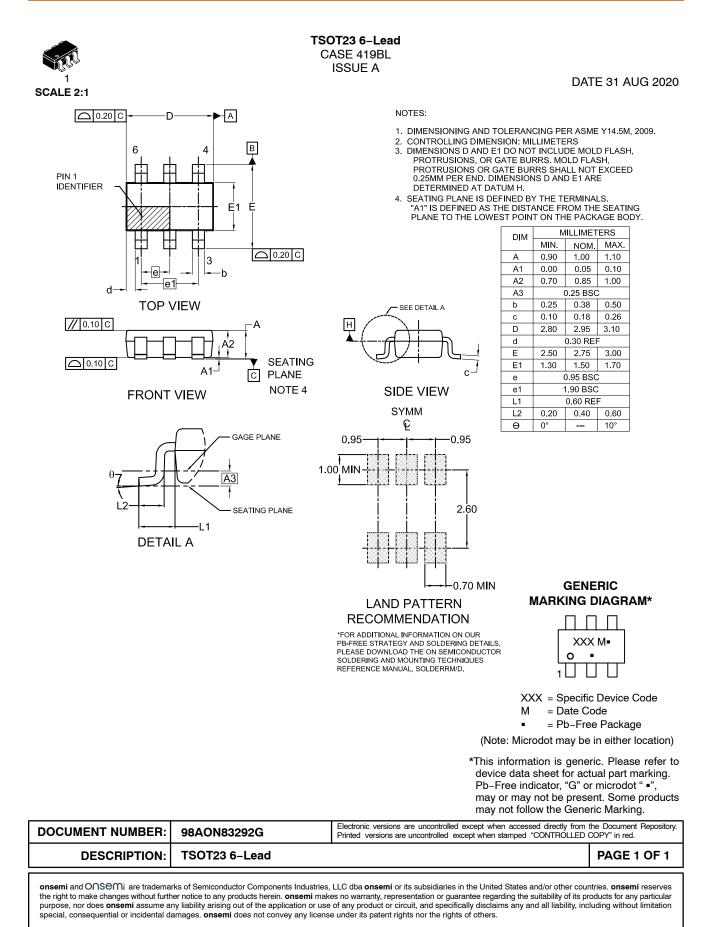


Figure 6. Capacitances

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